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ON Semiconductor® FDD9410-F085

N-Channel Power Trench[®] MOSFET

40 V, 50 A, 4.1 mΩ

Features

- Typ r_{DS(on)} = 3.5 mΩ at V_{GS} = 10V, I_D = 50 A
- Typ Q_{g(tot)} = 23.5 nC at V_{GS} = 10V, I_D = 50 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Integrated Starter/alternator
- Primary Switch for 12V Systems

MOSFET Maximum Ratings T_J = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V _{DSS}	Drain to Source Voltage		40	V
V _{GS}	Gate to Source Voltage		±20	V
I _D	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	50	^
	Pulsed Drain Current	T _C = 25°C	See Figure4	Α
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	40	mJ
P _D	Power Dissipation		75	W
	Derate Above 25°C		0.5	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance Junction to Case		2	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance Junction to Ambient	(Note 3)	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD9410	FDD9410-F085	D-PAK(TO-252)	13"	12mm	2500 units

Notes:

1: Current is limited by bondwire configuration.

2: Starting T_J = 25°C, L = 50uH, I_{AS} = 40A, V_{DD} = 40V during inductor charging and V_{DD} = 0V during time in avalanche. 3: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder ⁴⁰⁷ mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.



G

D

D-PAK (TO-252)

Symbol	Parameter	Test Conditions		Min	Тур	Мах	Units	
Off Cha	racteristics							
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		40	-	-	V	
1	Drain to Source Leakage Current	V _{DS} = 40V,	T _J =	25°C	-	-	1	μA
DSS		$V_{GS} = 0V$	T _J =	175ºC(Note 4)	-	-	1	mA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$			-	-	±100	nA
r _{DS(on)}	Drain to Source On Resistance	$I_{\rm D} = 50A$,	ון = ד		-	3.5	4.1	mΩ
. ,		V _{GS} = 10V	= ا _ا	175ºC(Note 4)	-	6.1	7.1	mΩ
Jynami	c Characteristics							
C _{iss}	Input Capacitance	1/25/(-)	/ C		-	1715	-	pF
C _{oss}	Output Capacitance	— V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	453	-	pF	
C _{rss}	Reverse Transfer Capacitance			-	28	-	pF	
R _g	Gate Resistance	f = 1MHz		-	2.3	-	Ω	
Q _{g(ToT)}	Total Gate Charge at 10V	$V_{GS} = 0$ to 10		V _{DD} = 20V	-	23.5	34.5	nC
Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0$ to 2	/	I _D = 50A	-	3.2	4	nC
Q _{gs}	Gate to Source Gate Charge				-	9.6	-	nC
\cap	Cata to Drain "Millor" Chargo					11		nC

Switching Characteristics

Gate to Drain "Miller" Charge

t _{on}	Turn-On Time		-	-	38	ns
t _{d(on)}	Turn-On Delay Time		-	12	-	ns
t _r	Rise Time	V _{DD} = 20V, I _D = 50A, V _{GS} = 10V, R _{GEN} = 6Ω	-	12	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{GS} = 10V, R _{GEN} = 6Ω	-	20	-	ns
t _f	Fall Time		-	9	-	ns
t _{off}	Turn-Off Time		-	-	45	ns

-

4.4

-

nC

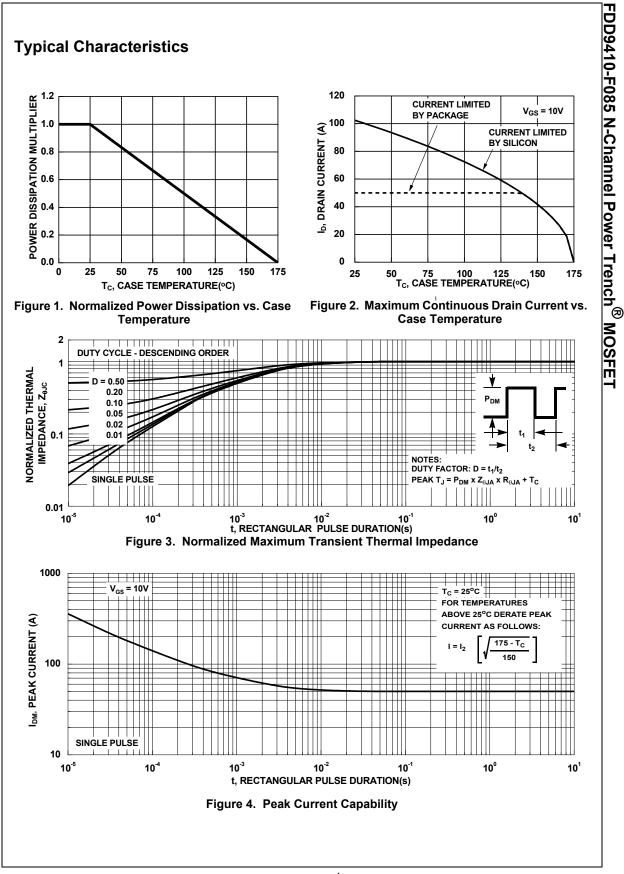
Drain-Source Diode Characteristics

\/	Source to Drain Diode Voltage	I _{SD} = 50A, V _{GS} = 0V	-	-	1.25	V
V _{SD}	Source to Drain Diode Voltage	I_{SD} = 25A, V_{GS} = 0V	-	-	1.2	V
T _{rr}	Reverse Recovery Time	I _F = 50A, dI _{SD} /dt = 100A/μs,	-	44	58	ns
Q _{rr}	Reverse Recovery Charge	V _{DD} =32V	-	31.5	41	nC

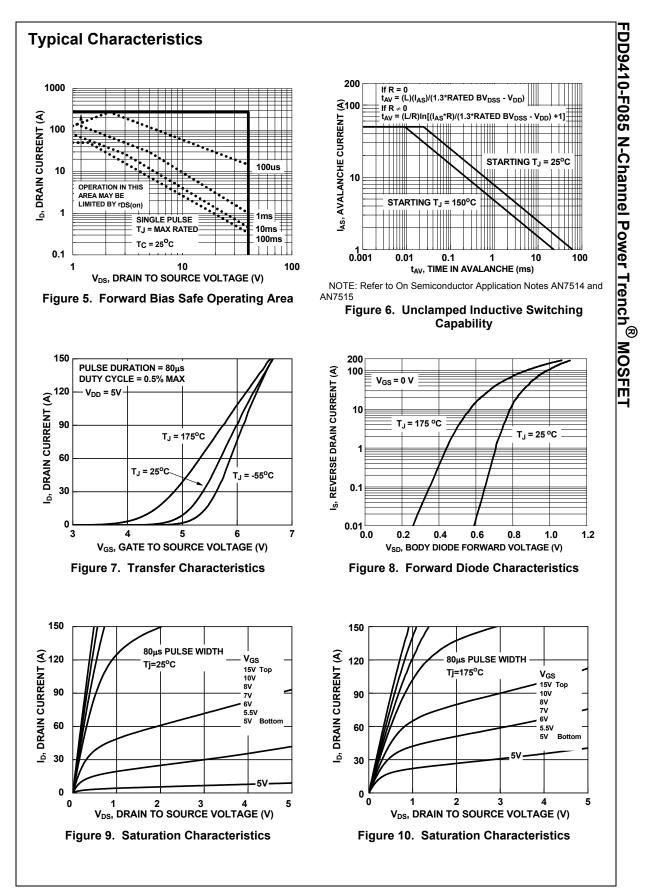
Note:

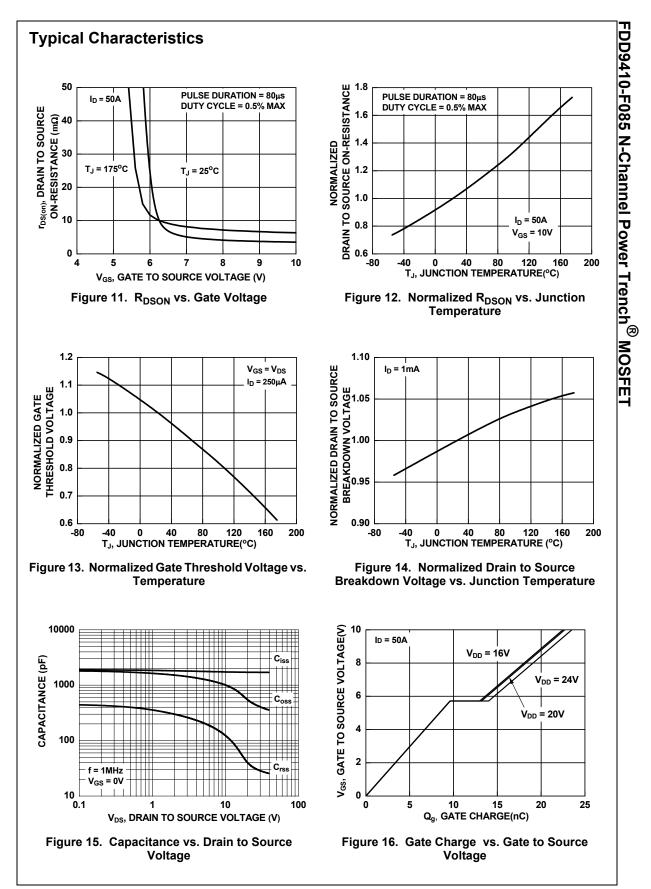
Q_{gd}

4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.



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